

P-Channel Enhancement-Mode Vertical DMOS FET

Features

- -2V Maximum Low Threshold
- High Input Impedance
- Low Input Capacitance
- Fast Switching Speeds
- Low On-Resistance
- Free from Secondary Breakdown
- Low Input and Output Leakage

Applications

- Logic-Level Interfaces (Ideal for TTL and CMOS)
- Solid State Relays
- Battery-Operated Systems
- Photovoltaic Drives
- Analog Switches
- General Purpose Line Drivers
- Telecommunication Switches

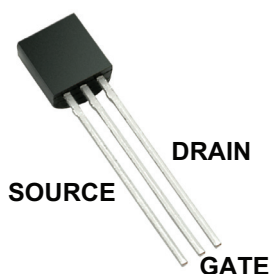
General Description

The TP2640 is a low-threshold, Enhancement-mode (normally-off) transistor that uses an advanced vertical DMOS structure and a well-proven silicon gate manufacturing process. This combination produces a device with the power handling capabilities of bipolar transistors and the high input impedance and positive temperature coefficient inherent in MOS devices. Characteristic of all MOS structures, this device is free from thermal runaway and thermally induced secondary breakdown.

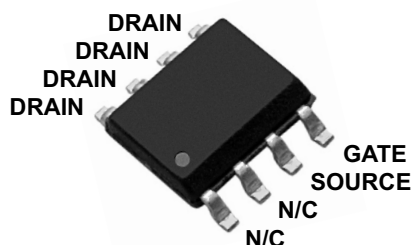
Microchip's vertical DMOS FETs are ideally suited to a wide range of switching and amplifying applications where high breakdown voltage, high input impedance, low input capacitance, and fast switching speeds are desired.

Package Type

3-lead TO-92
(Top view)



8-lead SOIC
(Top view)



See [Table 3-1](#) and [Table 3-2](#) for pin information.

TP2640

1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings†

Drain-to-Source Voltage	BV_{DSS}
Drain-to-Gate Voltage	BV_{DGS}
Gate-to-Source Voltage	$\pm 20V$
Operating Ambient Temperature, T_A	$-55^{\circ}C$ to $+150^{\circ}C$
Storage Temperature, T_S	$-55^{\circ}C$ to $+150^{\circ}C$

† **Notice:** Stresses above those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only, and functional operation of the device at those or any other conditions above those indicated in the operational sections of this specification is not intended. Exposure to maximum rating conditions for extended periods may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

Electrical Specifications: $T_A = 25^{\circ}C$ unless otherwise specified. All DC parameters are 100% tested at $25^{\circ}C$ unless otherwise stated. Pulse test: 300 μs pulse, 2% duty cycle.

Parameter	Sym.	Min.	Typ.	Max.	Unit	Conditions
Drain-to-Source Breakdown Voltage	BV_{DSS}	-400	—	—	V	$V_{GS} = 0V$, $I_D = -2$ mA
Gate Threshold Voltage	$V_{GS(th)}$	-0.8	—	-2	V	$V_{GS} = V_{DS}$, $I_D = -1$ mA
Change in $V_{GS(th)}$ with Temperature	$\Delta V_{GS(th)}$	—	—	5	mV/ $^{\circ}C$	$V_{GS} = V_{DS}$, $I_D = -1$ mA (Note 1)
Gate Body Leakage Current	I_{GSS}	—	—	-100	nA	$V_{GS} = \pm 20V$, $V_{DS} = 0V$
Zero-Gate Voltage Drain Current	I_{DSS}	—	—	-1	μA	$V_{GS} = 0V$, $V_{DS} = -100V$
				-10	mA	$V_{GS} = 0V$, $V_{DS} =$ Maximum rating
				-1	mA	$V_{DS} = 0.8$ Maximum rating, $V_{GS} = 0V$, $T_A = 125^{\circ}C$ (Note 1)
On-State Drain Current	$I_{D(ON)}$	-0.7	—	—	A	$V_{GS} = -10V$, $V_{DS} = -25V$
Static Drain-to-Source On-State Resistance	$R_{DS(ON)}$	—	12	15	Ω	$V_{GS} = -2.5V$, $I_D = -20$ mA
			11	15	Ω	$V_{GS} = -4.5V$, $I_D = -150$ mA
			11	15	Ω	$V_{GS} = -10V$, $I_D = -300$ mA
Change in $R_{DS(ON)}$ with Temperature	$\Delta R_{DS(ON)}$	—	—	0.75	%/ $^{\circ}C$	$V_{GS} = -10V$, $I_D = -300$ mA (Note 1)

Note 1: Specification is obtained by characterization and is not 100% tested.

AC ELECTRICAL CHARACTERISTICS

Electrical Specifications: $T_A = 25^\circ\text{C}$ unless otherwise specified. Specification is obtained by characterization and is not 100% tested.

Parameter	Sym.	Min.	Typ.	Max.	Unit	Conditions
Forward Transconductance	G _{FS}	200	—	—	mmho	V _{DS} = −25V, I _D = −300 mA
Input Capacitance	C _{ISS}	—	—	300	pF	V _{GS} = 0V, V _{DS} = −25V, f = 1 MHz
Common-Source Output Capacitance	C _{OSS}	—	—	50	pF	
Reverse Transfer Capacitance	C _{RSS}	—	—	12	pF	
Turn-On Delay Time	t _{d(ON)}	—	—	10	ns	V _{DD} = −25V, I _D = −300 mA, R _{GEN} = 25Ω
Rise Time	t _r	—	—	15	ns	
Turn-Off Delay Time	t _{d(OFF)}	—	—	60	ns	
Fall Time	t _f	—	—	40	ns	
DIODE PARAMETER						
Diode Forward Voltage Drop	V _{SD}	—	—	1.8	V	V _{GS} = 0V, I _{DS} = −200 mA (Note 1)
Reverse Recovery Time	t _{rr}	—	300	—	ns	V _{GS} = 0V, I _{DS} = −200 mA

Note 1: Unless otherwise stated, all DC parameters are 100% tested at 25°C . Pulse test: 300 μs pulse, 2% duty cycle

TEMPERATURE SPECIFICATIONS

Parameter	Sym.	Min.	Typ.	Max.	Unit	Conditions
TEMPERATURE RANGE						
Operating Ambient Temperature	T_A	-55	—	+150	$^\circ\text{C}$	
Storage Temperature	T_S	-55	—	+150	$^\circ\text{C}$	
PACKAGE THERMAL RESISTANCE						
3-lead TO-92	θ_{JA}	—	132	—	$^\circ\text{C/W}$	
8-lead SOIC	θ_{JA}	—	101	—	$^\circ\text{C/W}$	

THERMAL CHARACTERISTICS

Package	I_D (Note 1) (Continuous) (mA)	I_D (Pulsed) (mA)	Power Dissipation at $T_A = 25^\circ\text{C}$ (W)	I_{DR} (Note 1) (mA)	I_{DRM} (mA)
3-lead TO-92	-180	-800	1	-180	-800
8-lead SOIC	-86	-600	0.74 (Note 2)	-86	-600

Note 1: I_D (continuous) is limited by maximum T_J .

2: Mounted on an FR board, 25 mm x 25 mm x 1.57 mm

2.0 TYPICAL PERFORMANCE CURVES

Note: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g. outside specified power supply range) and therefore outside the warranted range.

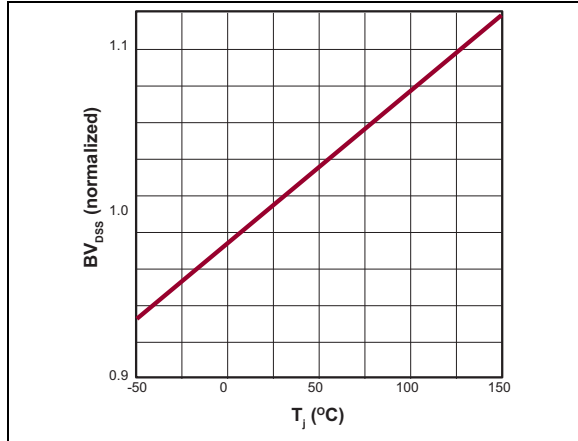


FIGURE 2-1: BV_{DSS} Variation with Temperature.

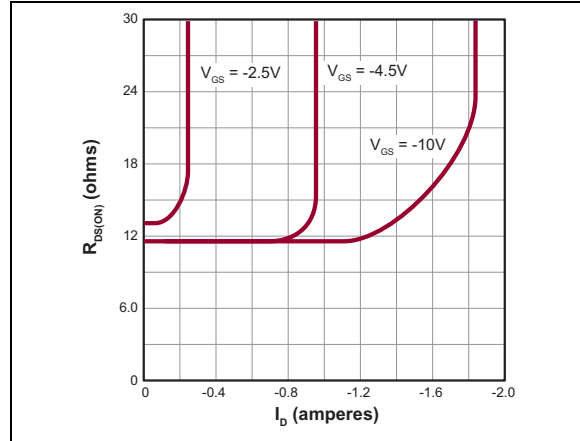


FIGURE 2-4: On-Resistance vs. Drain Current.

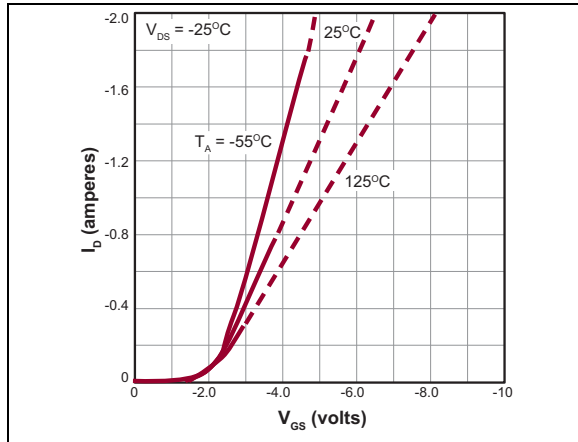


FIGURE 2-2: Transfer Characteristics.

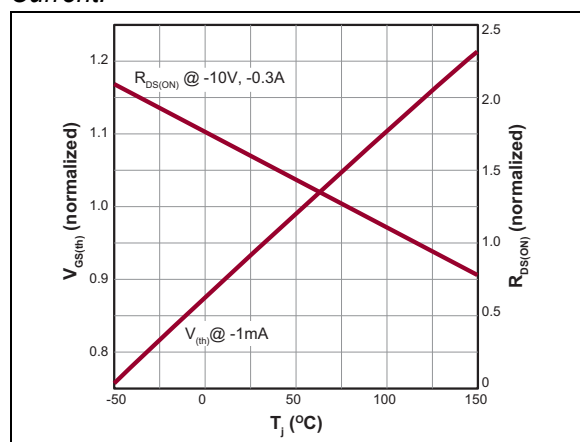


FIGURE 2-5: $V_{GS(th)}$ and R_{DS} Variation with Temperature.

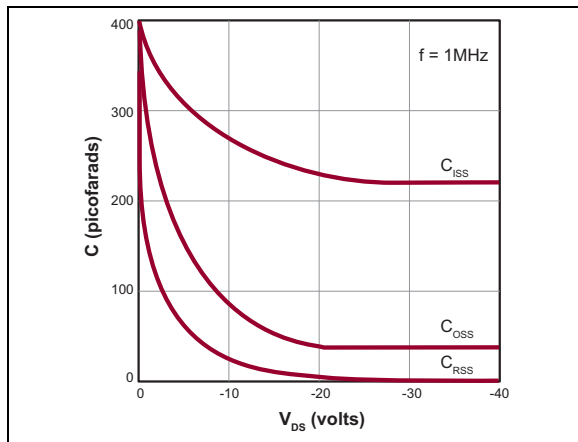


FIGURE 2-3: Capacitance vs. Drain-to-Source Voltage.

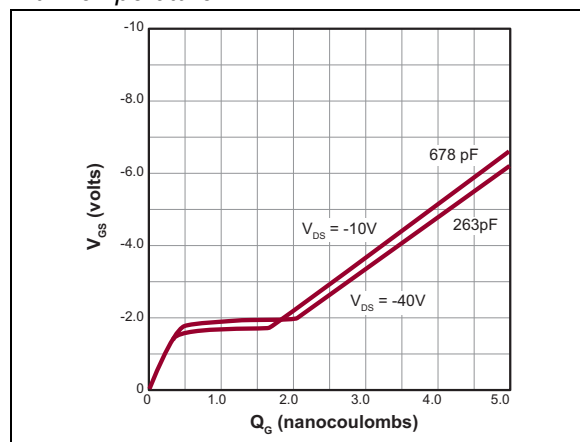


FIGURE 2-6: Gate Drive Dynamic Characteristics.

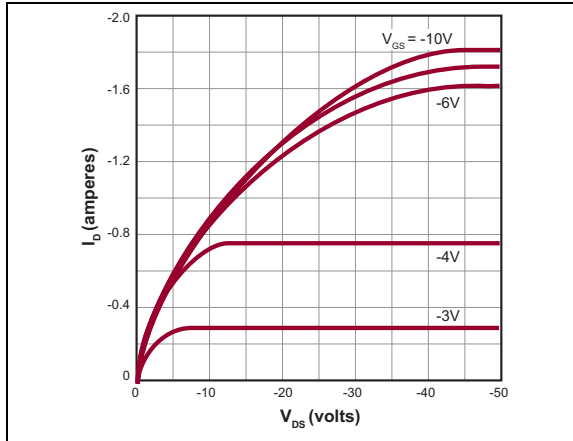


FIGURE 2-7: Output Characteristics.

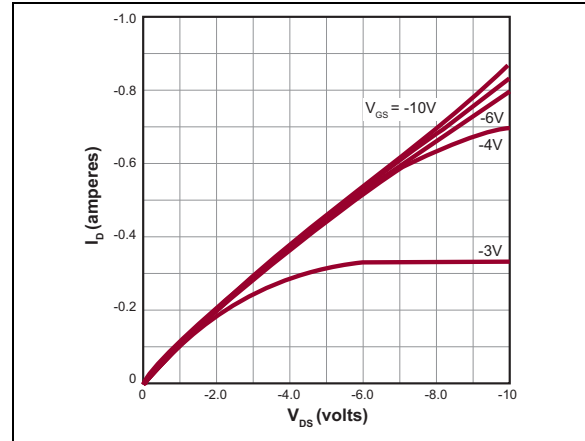


FIGURE 2-10: Saturation Characteristics.

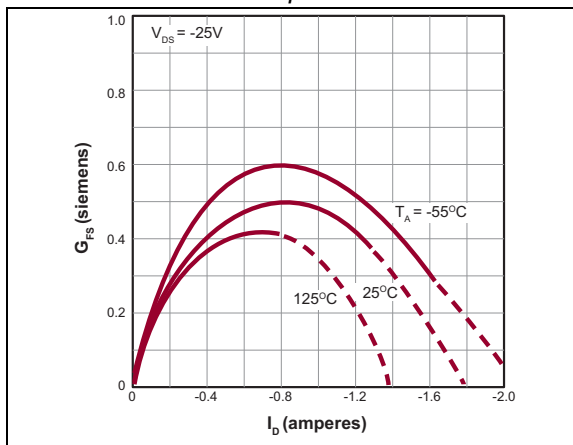


FIGURE 2-8: Transconductance vs. Drain Current.

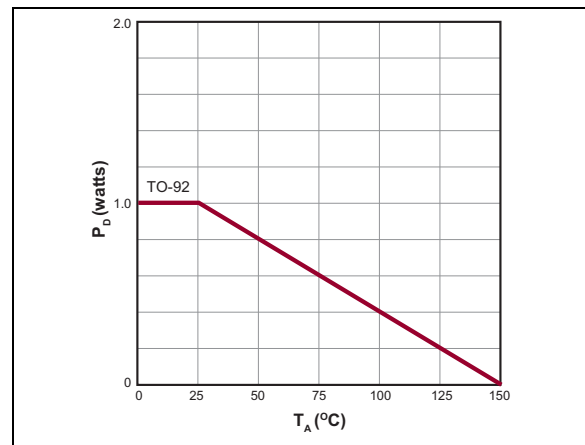


FIGURE 2-11: Power Dissipation vs. Temperature.

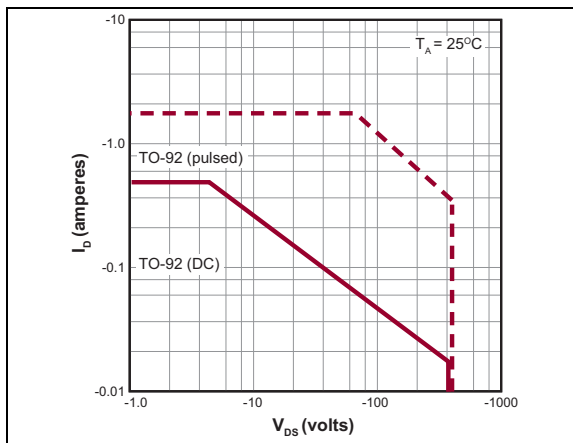


FIGURE 2-9: Maximum Rated Safe Operating Area.

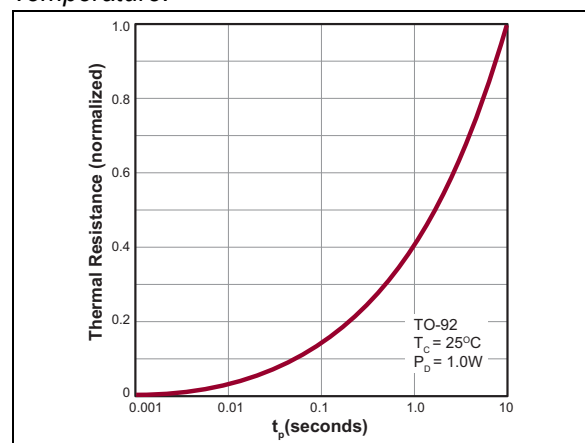


FIGURE 2-12: Thermal Response Characteristics.

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3.0 PIN DESCRIPTION

The details on the pins of TP2640 TO-92 and SOT-89 packages are listed in [Table 3-1](#) and [Table 3-2](#), respectively. Refer to [Package Type](#) for the location of pins.

TABLE 3-1: 3-LEAD TO-92 PIN FUNCTION TABLE

Pin Number	Pin Name	Description
1	Source	Source
2	Gate	Gate
3	Drain	Drain

TABLE 3-2: 8-LEAD SOIC PIN FUNCTION TABLE

Pin Number	Pin Name	Description
1	N/C	No Connection
2	N/C	No Connection
3	Source	Source
4	Gate	Gate
5	Drain	Drain
6	Drain	Drain
7	Drain	Drain
8	Drain	Drain

4.0 FUNCTIONAL DESCRIPTION

Figure 4-1 illustrates the switching waveforms and test circuit for TP2640.

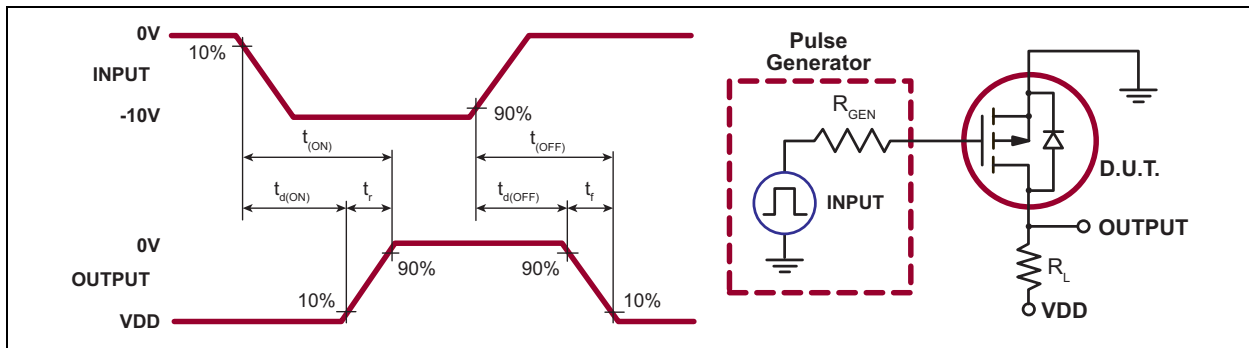


FIGURE 4-1: Switching Waveforms and Test Circuit.

TABLE 4-1: PRODUCT SUMMARY

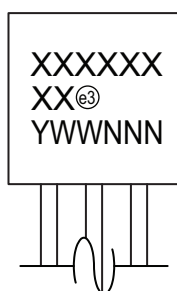
BV_{DSS}/BV_{DGS} (V)	$R_{DS(ON)}$ (Maximum) (Ω)	$I_{D(ON)}$ (Minimum) (A)	$V_{GS(th)}$ (Maximum) (V)
-400	15	-2	-0.7

TP2640

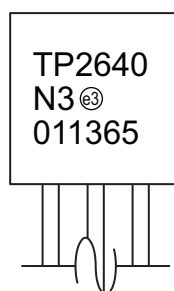
5.0 PACKAGING INFORMATION

5.1 Package Marking Information

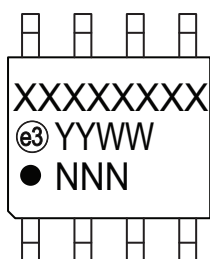
3-lead TO-92



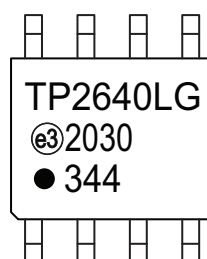
Example



8-lead SOIC



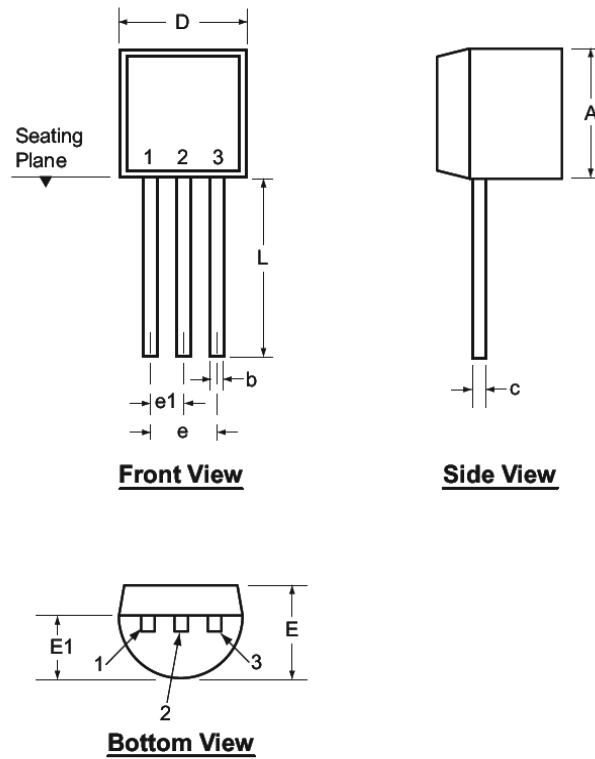
Example



Legend:	XX...X	Product Code or Customer-specific information
	Y	Year code (last digit of calendar year)
	YY	Year code (last 2 digits of calendar year)
	WW	Week code (week of January 1 is week '01')
	NNN	Alphanumeric traceability code
	^{e3}	Pb-free JEDEC [®] designator for Matte Tin (Sn)
	*	This package is Pb-free. The Pb-free JEDEC designator (^{e3}) can be found on the outer packaging for this package.

Note: In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for product code or customer-specific information. Package may or not include the corporate logo.

3-Lead TO-92 Package Outline (L/LL/N3)



Note: For the most current package drawings, see the Microchip Packaging Specification at www.microchip.com/packaging.

Symbol		A	b	c	D	E	E1	e	e1	L
Dimensions (inches)	MIN	.170	.014 [†]	.014 [†]	.175	.125	.080	.095	.045	.500
	NOM	-	-	-	-	-	-	-	-	-
	MAX	.210	.022 [†]	.022 [†]	.205	.165	.105	.105	.055	.610*

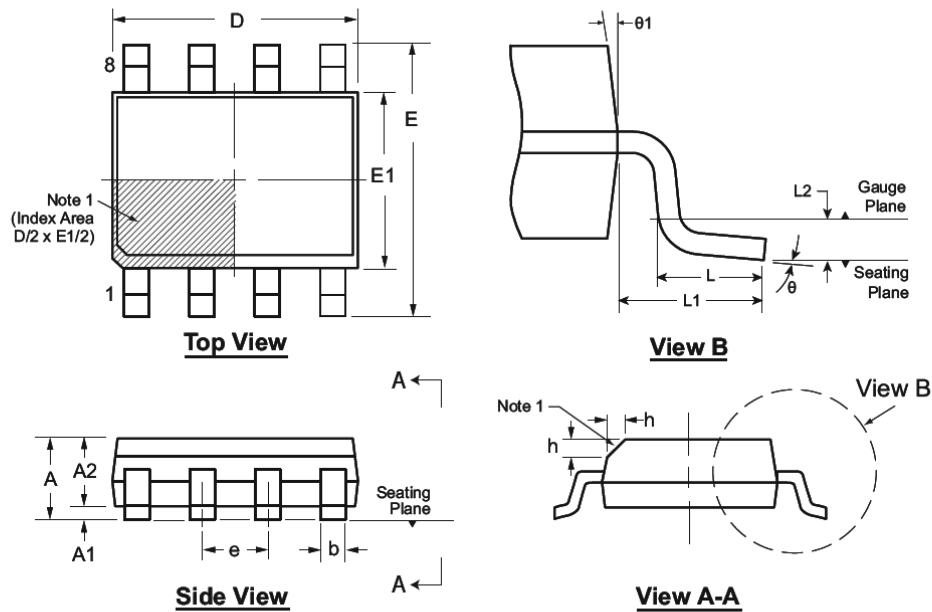
JEDEC Registration TO-92.

* This dimension is not specified in the JEDEC drawing.

† This dimension differs from the JEDEC drawing.

Drawings not to scale.

8-Lead SOIC (Narrow Body) Package Outline (LG/TG) 4.90x3.90mm body, 1.75mm height (max), 1.27mm pitch



Note: For the most current package drawings, see the Microchip Packaging Specification at www.microchip.com/packaging.

Note:

1. This chamfer feature is optional. A Pin 1 identifier must be located in the index area indicated. The Pin 1 identifier can be: a molded mark/identifier; an embedded metal marker; or a printed indicator.

Symbol		A	A1	A2	b	D	E	E1	e	h	L	L1	L2	θ	θ1
Dimension (mm)	MIN	1.35*	0.10	1.25	0.31	4.80*	5.80*	3.80*	1.27 BSC	0.25	0.40	1.04 REF	0.25 BSC	0°	5°
	NOM	-	-	-	-	4.90	6.00	3.90		-	-			-	-
	MAX	1.75	0.25	1.65*	0.51	5.00*	6.20*	4.00*		0.50	1.27			8°	15°

JEDEC Registration MS-012, Variation AA, Issue E, Sept. 2005.

* This dimension is not specified in the JEDEC drawing.

Drawings are not to scale.

APPENDIX A: REVISION HISTORY

Revision A (July 2020)

- Converted Supertex Doc# DSFP-TP2640 to Microchip DS20006372A
- Changed the package marking format
- Updated the quantity of the 8-lead SOIC LG package from 2500/Reel to 3300/Reel to align it with the actual BQM
- Removed the P002, P003, P005, P013, P014 media types for the 3-lead TO-92 N3 package
- Made minor text changes throughout the document

TP2640

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, contact your local Microchip representative or sales office.

<u>PART NO.</u>	<u>XX</u>	-	<u>X</u>	-	<u>X</u>
Device	Package Options		Environmental		Media Type
Device:	TP2640	=	P-Channel Enhancement-Mode Vertical DMOS FET		
Packages:	N3	=	3-lead TO-92		
	LG	=	8-lead SOIC		
Environmental:	G	=	Lead (Pb)-free/RoHS-compliant Package		
Media Types:	(blank)	=	1000/Bag for an N3 Package		
	(blank)	=	3300/Reel for an LG Package		

Examples:

a) TP2640N3-G: P-Channel Enhancement-Mode Vertical DMOS FET, 3-lead TO-92, 1000/Bag

b) TP2640LG-G: P-Channel Enhancement-Mode Vertical DMOS FET, 8-lead SOIC, 3000/Reel

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